

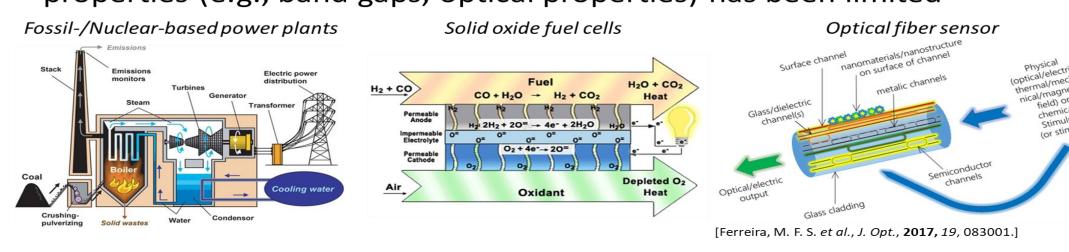
COLLABORATION WORKSHOP

Theoretical Study of Temperature Dependence and Optical properties of Gas Sensor Materials

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Introduction

- For advanced real-time monitoring, control of gas species in combustion environments, developing efficient sensing platforms and materials under harsh environments are required
- Semiconducting optical-based sensor platform can be promising; however, examining impact of operating conditions on functional sensor properties (e.g., band gaps, optical properties) has been limited



- For high-temperature gas sensor materials, understanding temperature dependence of relevant features is valued; temperature effect on electronic and optical properties originates from the electron-phonon coupling which perturbs the atomic motions
- MO_x metal-oxides and ABO₃ perovskite-oxides can be attractive for high-temperature applications due to high decomposition temperatures and structural stability; ABO₃ allows tunable electronic and optical properties owing to flexible design space by choices of A, B, and forming oxygen non-stoichiometry point-defects
- First-principles modeling assesses the temperature dependence of band gap renormalizations and optical properties, of which are vital for determining performance of the high-temperature sensors

Methods

- Density functional theory (DFT)
- PAW-PBE(+U) exchange-correlation in GGA (e.g., electronic structures)
- Optical properties from the frequency dependent dielectric function

$$\varepsilon(\omega) = \varepsilon_1(\omega) + i\varepsilon_2(\omega) = (n + ik)^2 = \frac{4\pi i}{\omega}\sigma(\omega)$$

- Formation energy of oxygen vacancy v_0^q in $ABO_{3-\delta}(q: charge states)$

$$\Delta H^{q}(ABO_{3}, v_{O}^{q}) = E^{q}(ABO_{3}, v_{O}^{q}) - E(ABO_{3}) + \mu_{O}(T, P) + qE_{F} + E_{corr} + \Delta F^{q}(T)$$

- Allen-Heine-Cardona (AHC) theory
- Lattice thermal expansion and, most dominantly, electron-phonon coupling contribute on renormalization of the band gaps
- Prediction of electron-phonon coupling effect on eigenstate energy level shifts $\Delta \epsilon_{nk}(T)$, in harmonic phonon approximation

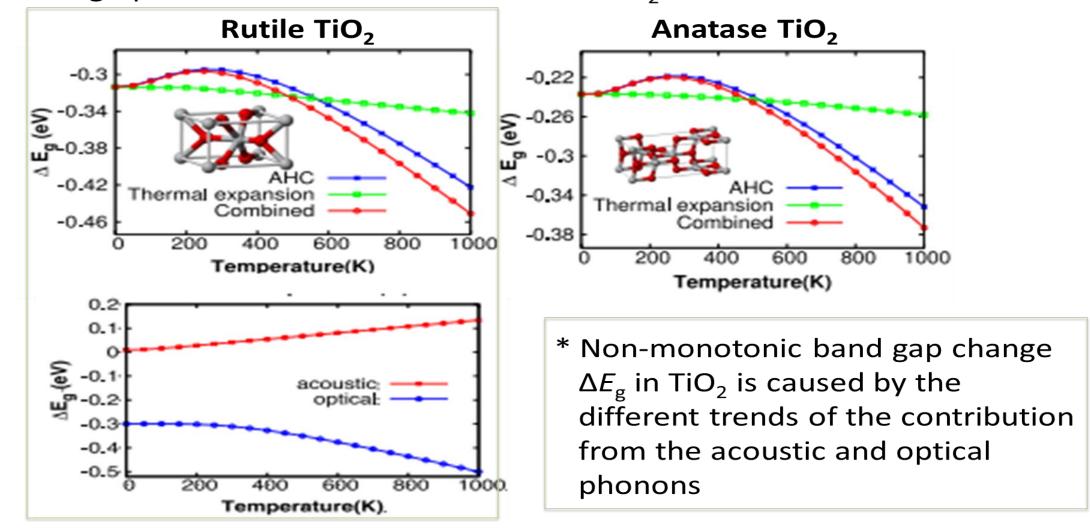
$$\Delta \epsilon_{nk}(T) = \frac{1}{N_q} \sum_{\boldsymbol{q}, \boldsymbol{\nu}} \frac{a_{\boldsymbol{q}\boldsymbol{\nu}; \boldsymbol{q}\boldsymbol{\nu}}^{(2)}}{\omega_{\boldsymbol{q}\boldsymbol{\nu}}} \left[\frac{1}{2} + n_B (\omega_{\boldsymbol{q}\boldsymbol{\nu}}, T) \right]$$

- Frozen-phonon method
- Optical properties calculation at finite temperatures
- Configurational averaging of optical properties using temperaturedependent configurations incorporating the atomic displacements u_n by phonons

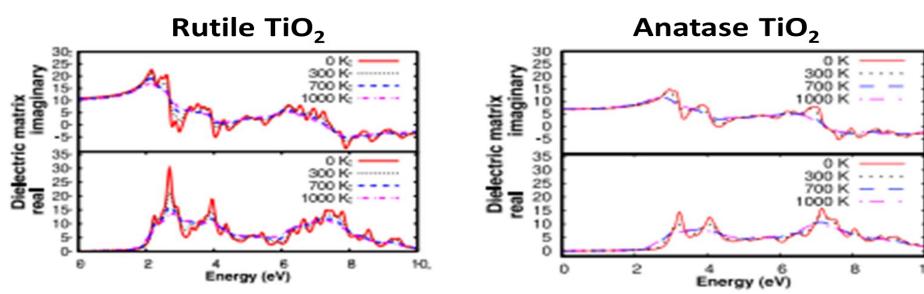
$$u_n = \sum_{\boldsymbol{q}, v} u_{n, \boldsymbol{q}v} = \sqrt{\frac{\hbar}{m_n}} \sum_{\boldsymbol{q}, v} \frac{\hat{n}_{\boldsymbol{q}v} e^{i(\boldsymbol{q} \cdot \boldsymbol{R}_n + \phi_{\boldsymbol{q}v})}}{\sqrt{(e^{\hbar \omega_{\boldsymbol{q}v}/k_B T} - 1)\omega_{\boldsymbol{q}v}}}$$

Metal-Oxides: TiO₂ and SnO_x

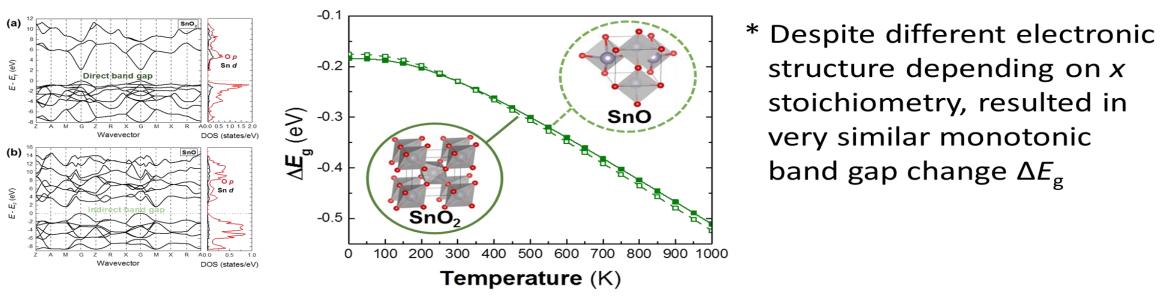
- Au/TiO₂ (Au-nanoparticle incorporated plasmonic oxides) have shown the potential for robust and reliable optical gas sensing properties at high working temperatures
- AHC calculations show the band gap widening up to ~ 300 K, followed by narrowing up to 1000 K in rutile and anatase TiO₂



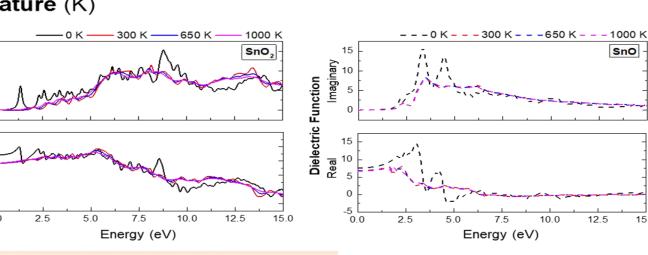
- Due to thermal smearing effect, the dielectric matrix (and resulting refraction index, extinction coefficient, and optical conductivity) spectra are greatly smoothened and broadened in rutile and anatase TiO₂



- SnO_x (x = 2, 1) are applied in many energy applications including catalysts, photovoltaics, and gas sensors
- AHC predictions show downshifts of the direct and indirect band gaps in SnO_x



- Change in the temperaturedependent optical properties is relevant to the above electronic structure variances



structure depending on x

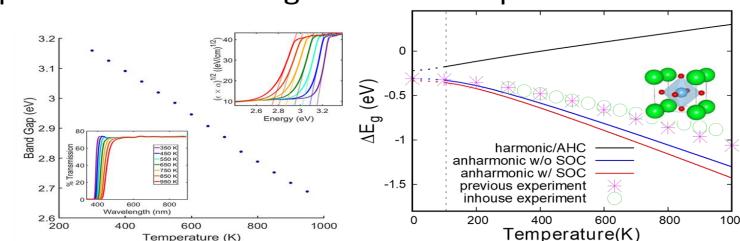
stoichiometry, resulted in

very similar monotonic

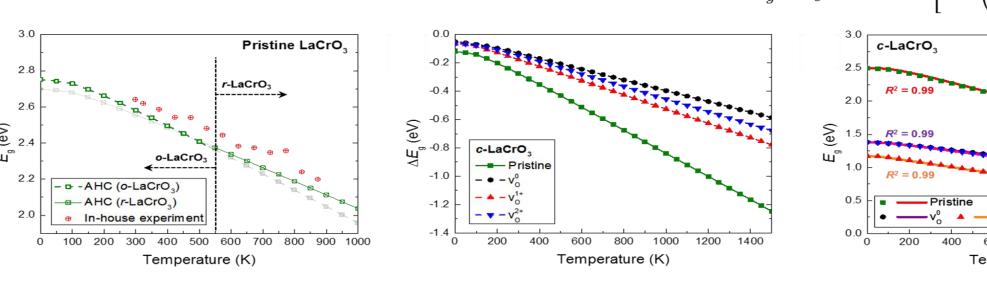
band gap change ΔE_g

Perovskite-Oxides: SrTiO₃ and LaCrO_{3-δ}

- In SrTiO₃, conventional harmonic phonons show soft modes, which leads AHC theory to predict incorrect trends of band gap change with temperature
- Self-consistent phonon approach to obtain the soft-mode-free phonons at finite temperature results in agreement to experiments

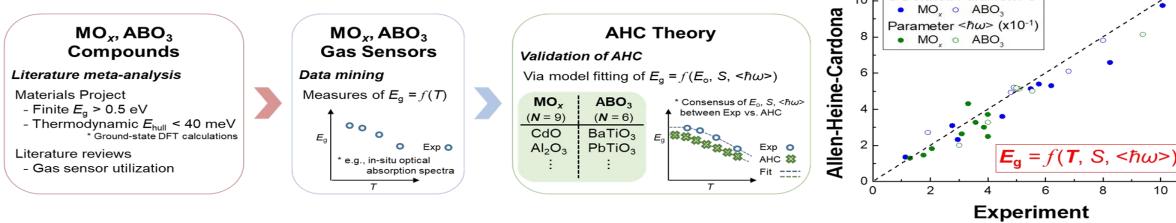


- Antiferromagnetic ordered, strongly-correlated LaCrO₃ undergoes structural phase transitions with temperature; **cubic** LaCrO₃ exists as a single phase at temperature relevant to the high-temperature application > 1000 K
- Quantitative agreement between AHC prediction and in-house experiment in temperature-dependent band gaps, with mild anomaly at phase transition T
- Band gap closure by 1.13 eV up to 1500 K in pristine cubic; analogous narrowing, but at lower magnitude by ~ 0.62 eV for oxygen-vacant v_0^q states
- O'Donnell model rationalizes the band gap shifts: $E_g = E_O S < \hbar\omega > \left[\coth\left(\frac{<\hbar\omega>}{2k_BT}\right) 1\right]$



Applicability of AHC Theory Towards Machine Learning

- Assess the consensus between the AHC theory and the measurements on temperature dependence of the band gaps in MO_x and ABO₃
- In conjunction with O'Donnell model to quantify the temperature dependence of band gaps using well-defined parameters



- Machine learning (ML) for predicting O'Donnell model parameters in MO_x
- Ultimately enables ML prediction of the temperature dependence of band gaps

Publications

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- Y.-N. Wu et al., J. Phys. Chem. C 122(2018) 22642-49; J. Phys. Chem. Lett. 11(2020) 2518-23; J. Phys. Condens. Matter 32(2020) 405705.
- T. Jia et al., RSC Adv. 7(2017) 38798-804; Phys. Chem. Chem. Phys. 22(2020) 16721-16726; Appl. Energy 281 (2021)116040; **J. Phys. Chem. C 125**(2021) 12374-81; **126**(2022)11421-25
- Y. Duan et al., J. Solid State Chem. 256(2017) 239-251. S. Nations, et al., RSC Adv. 11(2021) 22264-72; Mater. Adv. 3(2022)3897-3905

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